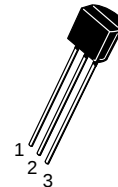
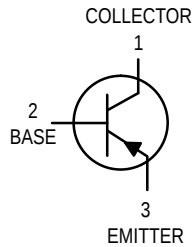


Amplifier Transistors

PNP Silicon

BC307,B,C
BC308C
BC309B



CASE 29-04, STYLE 17
TO-92 (TO-226AA)

MAXIMUM RATINGS

Rating	Symbol	BC 307	BC 308C	BC 309	Unit
Collector–Emitter Voltage	V_{CEO}	–45	–25	–25	Vdc
Collector–Base Voltage	V_{CBO}	–50	–30	–30	Vdc
Emitter–Base Voltage	V_{EBO}	–5.0			Vdc
Collector Current — Continuous	I_C	–100			mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	350 2.8			mW mW/°C
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.0 8.0			Watts mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150			°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	357	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	125	°C/W

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = -2.0$ mAdc, $I_B = 0$)	BC307 BC308C BC309B	$V_{(BR)CEO}$	–45 –25 –25	— — —	— — —	Vdc
Emitter–Base Breakdown Voltage ($I_E = -100$ μ Adc, $I_C = 0$)	BC307 BC308C BC309B	$V_{(BR)EBO}$	–5.0 –5.0 –5.0	— — —	— — —	Vdc
Collector–Emitter Leakage Current ($V_{CES} = -50$ V, $V_{BE} = 0$) ($V_{CES} = -30$ V, $V_{BE} = 0$)	BC307 BC308C BC309B	I_{CES}	— — —	–0.2 –0.2 –0.2	–15 –15 –15	nAdc
($V_{CES} = -50$ V, $V_{BE} = 0$) $T_A = 125^\circ\text{C}$	BC307		—	–0.2	–4.0	μ A
($V_{CES} = -30$ V, $V_{BE} = 0$) $T_A = 125^\circ\text{C}$	BC308C BC309B		— —	–0.2 –0.2	–4.0 –4.0	

BC307,B,C BC308C BC309B**ELECTRICAL CHARACTERISTICS** ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS					
DC Current Gain ($I_C = -10\ \mu\text{Adc}$, $V_{CE} = -5.0\ \text{Vdc}$)	h_{FE}	—	150	—	—
BC307B/309B		—	270	—	
BC307C/308C		—	—	—	
($I_C = -2.0\ \text{mAdc}$, $V_{CE} = -5.0\ \text{Vdc}$)		120	—	800	
BC307		120	—	800	
BC308C		—	—	—	
($I_C = -100\ \text{mAdc}$, $V_{CE} = -5.0\ \text{Vdc}$)		200	290	460	
BC307B/309B		420	500	800	
BC307C/308C		—	—	—	
BC307B/309B		—	180	—	
BC307C/308C		—	300	—	
Collector–Emitter Saturation Voltage ($I_C = -10\ \text{mAdc}$, $I_B = -0.5\ \text{mAdc}$)	$V_{CE(sat)}$	—	–0.10	–0.3	Vdc
($I_C = -10\ \text{mAdc}$, $I_B = \text{see Note 1}$)		—	–0.30	–0.6	
($I_C = -100\ \text{mAdc}$, $I_B = -5.0\ \text{mAdc}$)		—	–0.25	—	
Base–Emitter Saturation Voltage ($I_C = -10\ \text{mAdc}$, $I_B = -0.5\ \text{mAdc}$)	$V_{BE(sat)}$	—	–0.7	—	Vdc
($I_C = -100\ \text{mAdc}$, $I_B = -5.0\ \text{mAdc}$)		—	–1.0	—	
Base–Emitter On Voltage ($I_C = -2.0\ \text{mAdc}$, $V_{CE} = -5.0\ \text{Vdc}$)	$V_{BE(on)}$	–0.55	–0.62	–0.7	Vdc
DYNAMIC CHARACTERISTICS					
Current–Gain — Bandwidth Product ($I_C = -10\ \text{mAdc}$, $V_{CE} = -5.0\ \text{Vdc}$, $f = 100\ \text{MHz}$)	f_T	—	280	—	MHz
BC307		—	320	—	
BC308C		—	360	—	
BC309B		—	—	—	
Common Base Capacitance ($V_{CB} = -10\ \text{Vdc}$, $I_C = 0$, $f = 1.0\ \text{MHz}$)	C_{cbo}	—	—	6.0	pF
Noise Figure ($I_C = -0.2\ \text{mAdc}$, $V_{CE} = -5.0\ \text{Vdc}$, $R_S = 2.0\ \text{k}\Omega$, $f = 1.0\ \text{kHz}$)	NF	—	2.0	4.0	dB
BC309		—	2.0	10	
BC307		—	2.0	10	
($I_C = -0.2\ \text{mAdc}$, $V_{CE} = -5.0\ \text{Vdc}$, $R_S = 2.0\ \text{k}\Omega$, $f = 1.0\ \text{kHz}$, $f = 200\ \text{Hz}$)		—	2.0	10	
BC308C		—	2.0	4.0	
BC309B		—	2.0	4.0	

1. $I_C = -10\ \text{mAdc}$ on the constant base current characteristic, which yields the point $I_C = -11\ \text{mAdc}$, $V_{CE} = -1.0\ \text{V}$.

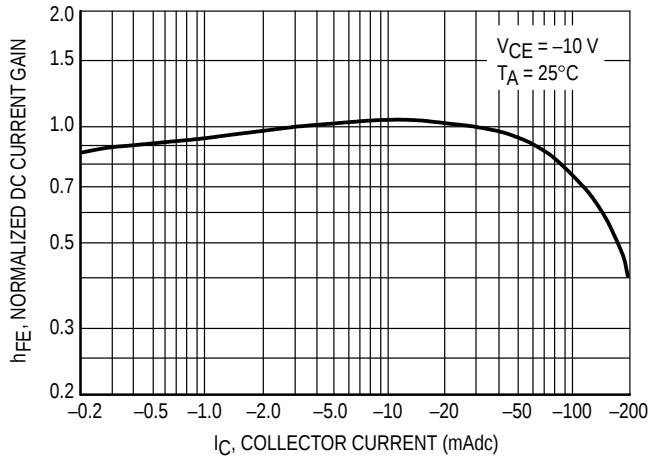


Figure 1. Normalized DC Current Gain

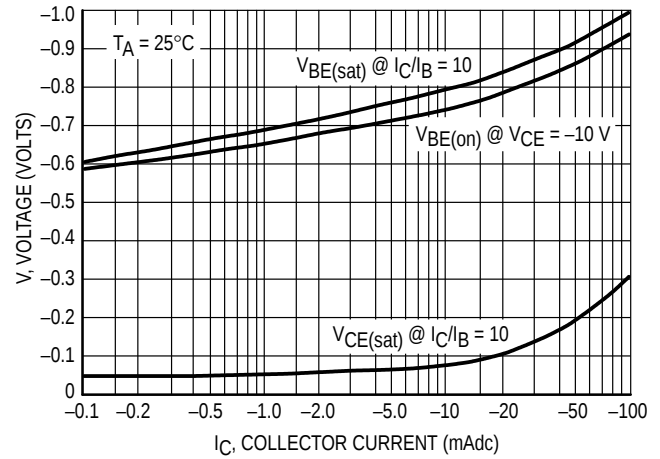


Figure 2. "Saturation" and "On" Voltages

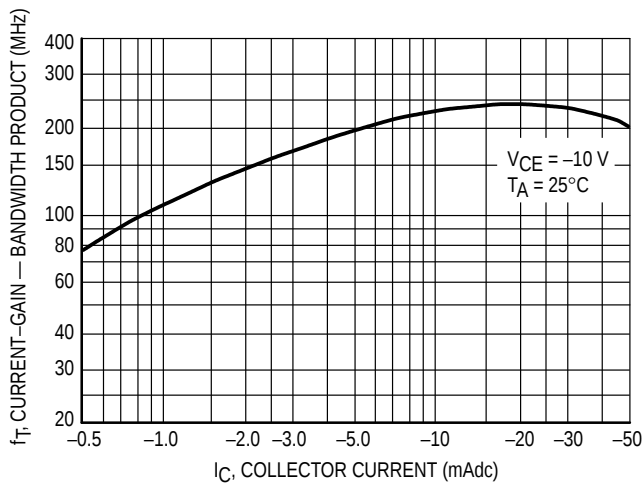


Figure 3. Current-Gain — Bandwidth Product

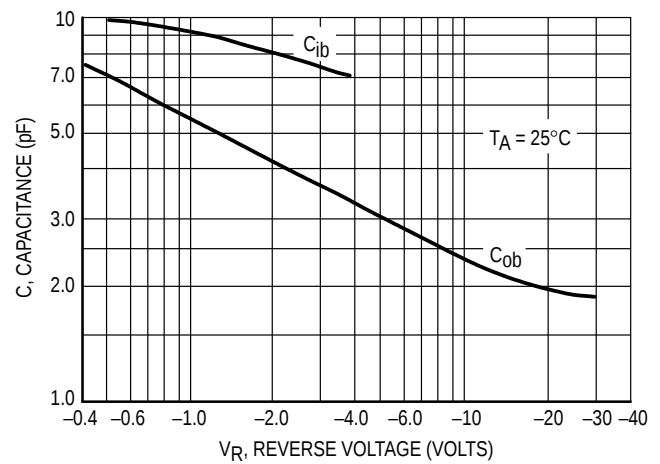


Figure 4. Capacitances

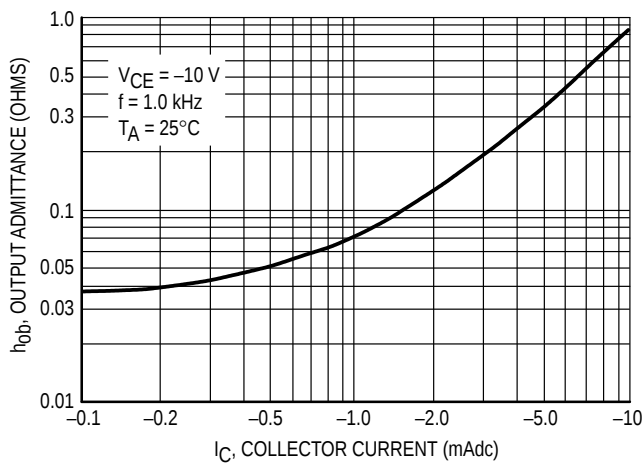


Figure 5. Output Admittance

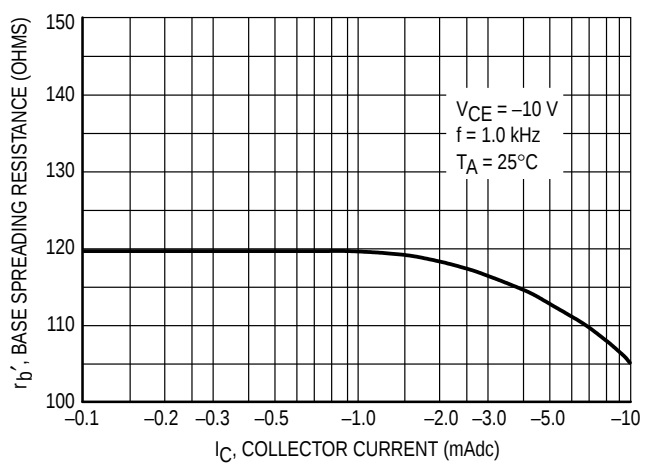
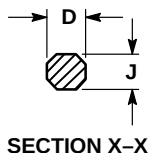
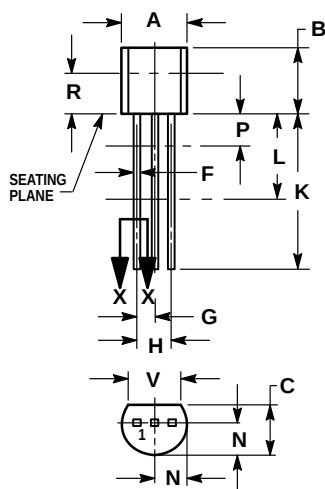


Figure 6. Base Spreading Resistance

PACKAGE DIMENSIONS



**CASE 029-04
(TO-226AA)
ISSUE AD**

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K. MINIMUM LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

STYLE 17:

1. COLLECTOR
2. BASE
3. EMITTER

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